Freeform Search

Database:
US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Term: memory same mode same 115

Display: 10 **Documents in Display Format:** ___ **Starting with Number** 1

Generate: ○ Hit List ● Hit Count ○ Side by Side ○ Image

[Search] [Clear] [Interrupt]

Search History

DATE: Monday, November 07, 2005 Printable Copy Create Case

Set Name side by side	Query	Hit Count	Set Name result set
	DB=PGPB,USPT,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ		
L16	memory same mode same 115	4	L16
L15	(erasable adj2 ((non adj volatile) or PROM or flash)) same (non adj2 erasable)	53	L15
L14	l7 and l2	1	L14
L13	5768182.uref.	15	L13
L12	(operate or operating) same (memory) same mode same (erasable or volatile) same (non adj erasable)	3	L12
L11	(operate or operating) adj4 (memory) adj4 mode adj4 (write or writing)	28	L11
L10	L9 and l8 and l7	1	L10
L9	soft adj2 (write or writing)	387	L9
L8	hard adj2 (write or writing)	668	L8
L7	(operate or operating) adj4 (memory) adj4 mode	1029	L7
L6	L5 same (selecting or select)	55	L6
L5	L3 same ROM same RAM same (non adj volatile)	578	L5
L4	L3 and l2	15	L4

L3	memory same mode	165292	L3
L2	programmable metallization cell	184	L2
L1	prgrammable metallization cell	1	L1

END OF SEARCH HISTORY